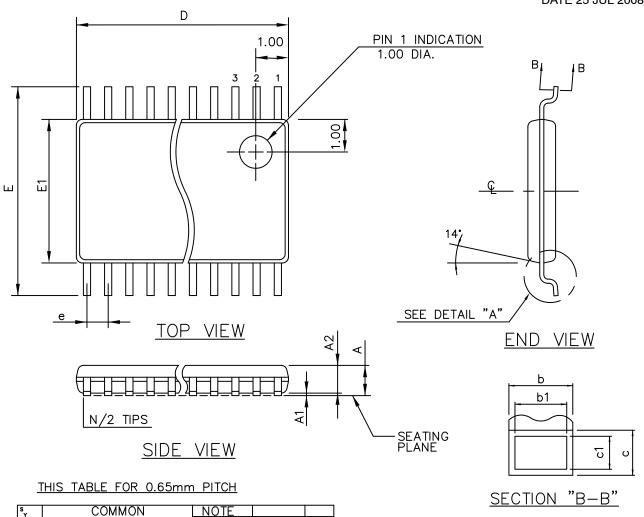
TSSOP 14 CASE 948AE-01 ISSUE O

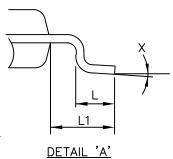
DATE 25 JUL 2008



۰,	1	COMMON	1	NOIE			
Y _{MB}	DII	MENSION	1S	VARI-			N
٩	MIN.	NOM.	MAX.	ATIONS	L	,	IN
Α			1.10	AA/AAT	3.00	BSC	8
Αı	0.05		0.15	AB-1/ABT	5.00	BSC	14
A2	0.85	0.90	0.95	AB/ABT	5.00	BSC	16
σ	0.19	_	0.30	AD/ADT	7.80	BSC	24
b1	0.19	0.22	0.25				
O	0.09	_	0.20				
c1	0.09	0.127	0.16				
D	SEE	VARIATIO	NS				
E1	4.30	4.40	4.50				

0.70

ALL DIMENSIONS IN MILLIMETERS



MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15mm ON D PER SIDE

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DESCRIPTION:	TSSOP 14		PAGE 1 OF 1			

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0.65 BSC 6.40 BSC

0.60

VARIATIONS

1.00 REF

<u>L1</u>

N X